



AM Series Intensity Modulator



Description

The LiNbO₃ intensity modulator is widely used in high-speed optical communication system, laser sensing and ROF systems because of well electro-optic performance. The R-AM series based on MZ push-pull structure and X-cut design, has stable physical and chemical characteristics, which can be applied both in laboratory experiments and industrial systems.

Features

- Low insertion loss
- High Bandwidth
- Low half-wave voltage
- Customization option

Applications

- ROF systems
- Quantum key distribution
- Laser sensing systems
- Side-band modulation

Wavelength

- 850nm
- 1064nm
- 1310nm
- 1550nm

Bandwidth

- 300MHz
- 2.5GHz
- 10GHz
- 20GHz

Operating wavelength	850nm	1064nm	1310nm	1550nm	
3dB Bandwidth	~10GHz	~10GHz	~10GHz	~10GHz	~20GHz
Insertion Loss	<5dB	< 5dB	< 5dB	< 5dB	
Extinction ratio @DC	> 23dB	> 23dB	> 23dB	> 23dB	
V _H @RF (1KHz)	< 3V	< 4V	<4.5V	<5.5V	<6V
V _H @Bias	< 3.5V	<5V	<6V	<7V	

Ordering Information

R	AM	15	10G	XX	XX
	Type: AM---Intensity Modulator	Wavelength: 08---850nm 10---1060nm 13---1310nm 15---1550nm	3dB bandwidth: 2.5G---10GHz 10G---10GHz 20G---20GHz 40G---28GHz	In-Out Fiber type: PP---PM/PM PS---PM/SMF	Optical connector: FA --- FC/APC FP --- FC/PC SP --- Customization

**R-AM-08-10G****Wavelength 850nm 10GHz Intensity modulator**

Parameter	Symbol	Min	Typ	Max	Unit			
Optical parameters								
Operating wavelength	λ	830	850	870	nm			
Insertion loss	IL		4.5	5	dB			
Optical return loss	ORL			-45	dB			
Switch extinction ratio @DC	ER@DC	20			dB			
Dynamic extinction ratio	DER		13		dB			
Optical fiber	Input port		850nm PM fiber(125/250μm)					
	output port		850nm PM fiber(125/250μm)					
Optical fiber interface		FC/PC、FC/APC Or Customization						
Electrical parameters								
Operating bandwidth (-3dB)	S_{21}	10	12		GHz			
Half-wave voltage V_{pi}	RF	@1KHz		2.5	3			
	Bias	@1KHz		3	4			
Electrical return loss	S_{11}		-12	-10	dB			
Input impedance	RF	Z_{RF}	50					
	Bias	Z_{BIAS}	1M					
Electrical interface		SMA(f)						

Limit Conditions

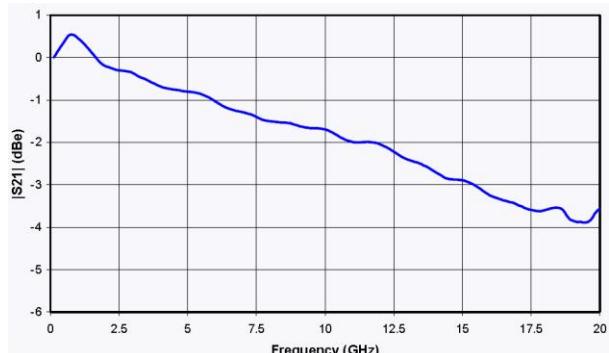
Parameter	Symbol	Unit	Min	Typ	Max
Input optical power@850nm	$P_{in,Max}$	dBm			10
Input RF power		dBm			28
bias voltage	V_{bias}	V	-15		15
Operating temperature	Top	°C	-10		60
Storage temperature	Tst	°C	-40		85
Humidity	RH	%	5		90



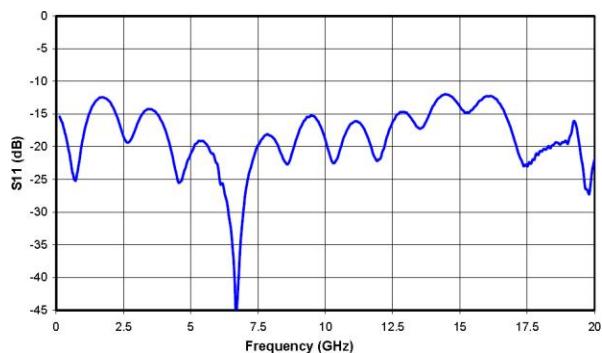
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S21 Curve

&S11 Curve

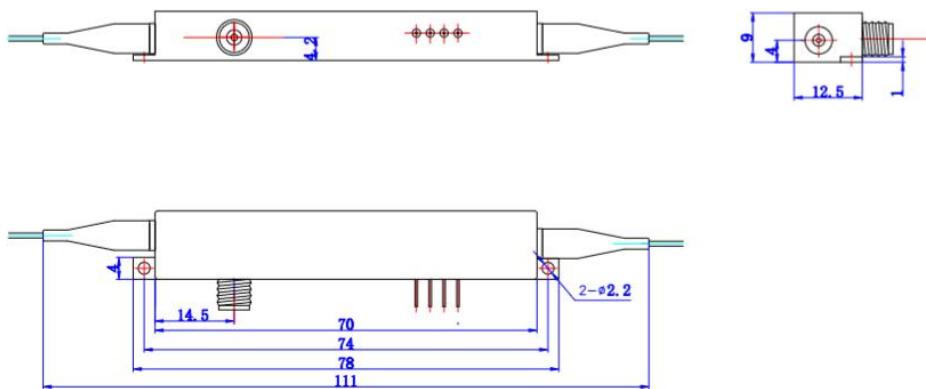


S21 Curve



S11 Curve

Mechanical Diagram



PORT	Symbol	Note
In	Optical input port	PM Fiber (125μm/250μm)
Out	Optical output port	PM and SMF option
RF	RF input port	SMA(f)
Bias	Bias control port	1,2 Bias, 34-N/C

RF Driver and Bias control circuit board information are provided on website (www.bjrofoc.com), you can also contact us for more information by email (bjrofoc@rof-oc.com) or WhatsApp (+86-18978968297)



R-AM-13

1310nm Intensity Modulator

The LiNbO₃ intensity modulator is widely used in high-speed optical communication system, laser sensing and ROF systems because of well electro-optic effect. The R-AM series based on MZ structure and X-cut design, has stable physical and chemical characteristics, which can be applied both in laboratory experiments and industrial systems.

Features

- Low insertion loss
- Bandwidth: 2.5GHz
- Low half-wave voltage
- Customization option

Applications

- ROF systems
- Quantum key distribution
- Laser sensing systems
- Side-band modulation



Optical parameters

Parameter	Symbol	Min	Typ	Max	Unit
Operating wavelength	λ	1290	1310	1330	nm
Insertion loss	IL		4	5	dB
Optical return loss	ORL			-45	dB
Switch extinction ratio @DC	ER@DC	20	23		dB
Dynamic extinction ratio	DER		13		dB
Optical fiber	Input port		PM Fiber (125/250μm)		
	output port		PM Fiber or SM Fiber (125/250μm)		
Optical fiber interface			FC/PC、 FC/APC Or Customization		



Electrical parameters

Parameter	Symbol	Min	Typ	Max	Unit
Operating bandwidth (-3dB)	S ₂₁		2.5		GHz
Half-wave voltage	RF	V _π @1KHz		3	V
	Bias	V _π @1KHz		3.5	V
Electrical return loss	S ₁₁		-12	-10	dB
Input impedance	RF	Z _{RF}	50		Ω
	Bias	Z _{BIAIS}	1M		Ω
Electrical interface			SMA(f)		

Limit

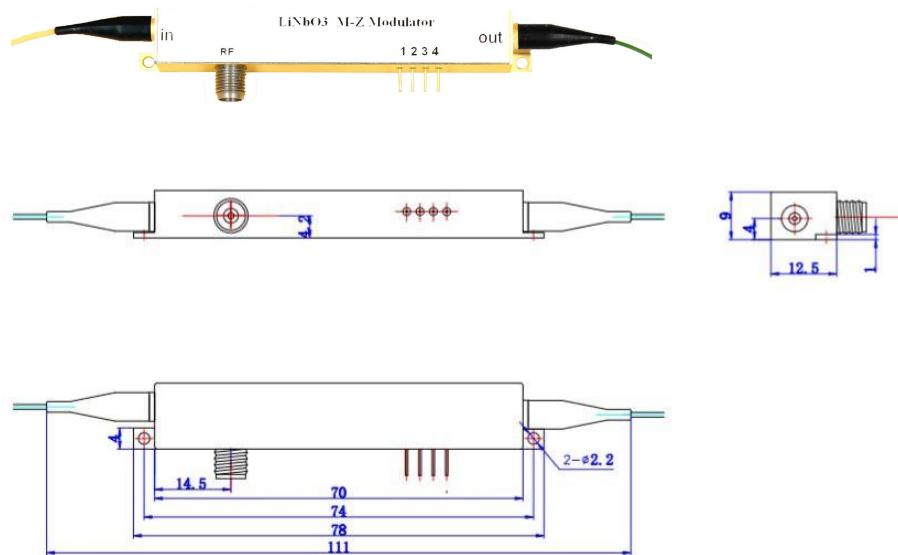
Parameter	Symbol	Unit	Min	Typ	Max
Input optical power	P _{in,Max}	dBm			20
Input RF power		dBm			28
bias voltage	V _{bias}	V	-15		15
Operating temperature	T _{op}	°C	-10		60
Storage temperature	T _{st}	°C	-40		85
Humidity	RH	%	5		90

Ordering information

R	AM	15	10G	XX	XX
	Type: AM---Intensity Modulator	Wavelength: 08---850nm 10---1060nm 13---1310nm 15---1550nm	Operating bandwidth: 2.5G---10GHz 10G---10GHz 20G---10GHz	In-Out Fiber type: PP---PM/PM PS---PM/SMF	Optical connector: FA---FC/APC FP---FC/PC XX---Customization



Mechanical Diagram



PORT	Symbol	Note
In	Optical input port	PM Fiber (125μm/250μm)
Out	Optical output port	PM and SM Fiber option
RF	RF input port	SMA(f)
Bias	Bias control port	1,2 Bias, 34-N/C

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- High Bandwidth
- Low half-wave voltage
- Customization option

Applications

- ROF systems
- Quantum key distribution
- Laser sensing systems
- Side-band modulation

Wavelength

- 850nm
- 1064nm
- 1310nm
- 1550nm

Bandwidth

- 300MHz
- 2.5GHz
- 10GHz
- 20GHz

Operating wavelength	850nm	1064nm	1310nm	1550nm	
3dB Bandwidth	~10GHz	~10GHz	~10GHz	~10GHz	~20GHz
Insertion Loss	<5dB	<5dB	<5dB	<5dB	
Extinction ratio @DC	> 23dB	> 23dB	> 23dB	> 23dB	
V _H @RF (1KHz)	< 3V	< 4V	< 4.5V	< 5.5V	< 6V
V _H @Bias	< 3.5V	< 5V	< 6V	< 7V	

Ordering Information

R	AM	15	10G	XX	XX
	Type: AM---Intensity Modulator	Wavelength: 08---850nm 10---1060nm 13---1310nm 15---1550nm	3dB bandwidth: 2.5G---10GHz 10G---10GHz 20G---20GHz 40G---28GHz	In-Out Fiber type: PP---PM/PM PS---PM/SMF	Optical connector: FA --- FC/APC FP --- FC/PC SP --- Customization

**R-AM-10-10G****Wavelength 1064nm 10GHz Intensity modulator**

Parameter	Symbol	Min	Typ	Max	Unit			
Optical parameters								
Operating wavelength	λ	980	1060	1150	nm			
Insertion loss	IL		4	5	dB			
Optical return loss	ORL			-45	dB			
Switch extinction ratio @DC	ER@DC	20	25		dB			
Dynamic extinction ratio	DER		13		dB			
Optical fiber	Input port		980nm PM fiber (125/250μm)					
	output port		980nm PM fiber (125/250μm)					
Optical fiber interface		FC/PC、FC/APC Or Customization						
Electrical parameters								
Operating bandwidth (-3dB)	S_{21}	10	12		GHz			
Half-wave voltage V _{pi}	RF	@50KHz		3.5	4			
	Bias	@Bias		4	5			
Electrical return loss	S_{11}		-12	-10	dB			
Input impedance	RF	Z_{RF}	50					
	Bias	Z_{BIAS}	1M					
Electrical interface		SMA(f)						

Limit Conditions

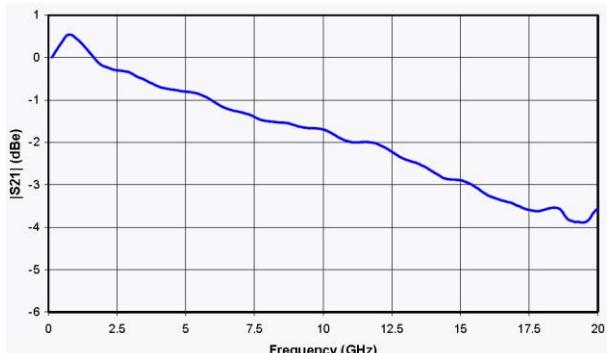
Parameter	Symbol	Unit	Min	Typ	Max
Input optical power	$P_{in,Max}$	dBm			20
Input RF power		dBm			28
bias voltage	V _{bias}	V	-15		15
Operating temperature	Top	°C	-10		60
Storage temperature	T _{st}	°C	-40		85
Humidity	RH	%	5		90



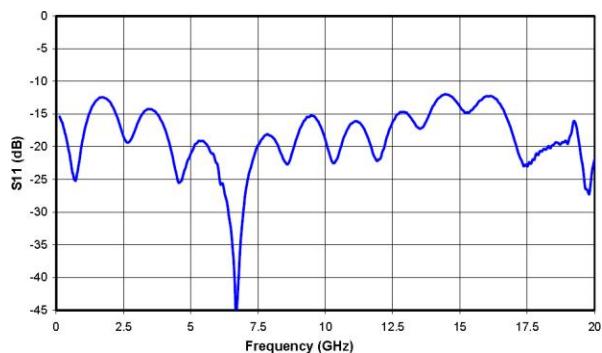
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S21 Curve

&S11 Curve

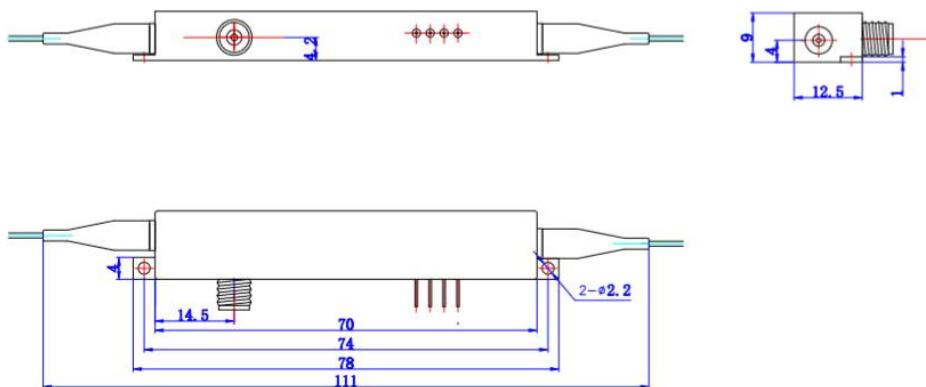


S21 Curve



S11 Curve

Mechanical Diagram



PORT	Symbol	Note
In	Optical input port	PM Fiber (125µm/250µm)
Out	Optical output port	PM and SMF option
RF	RF input port	SMA(f)
Bias	Bias control port	1,2 Bias, 34-N/C

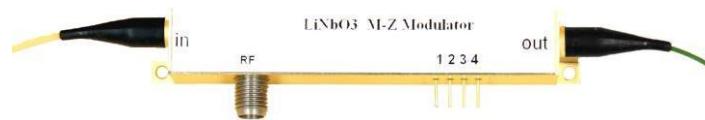
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Rof-AM 1064nm Intensity Modulator

Rof-AM series 1064nm lithium niobate electro-optic intensity modulator adopts advanced proton exchange technology. It has the characteristics of low insertion loss, high modulation bandwidth, low half-wave voltage and so on, and mainly used in space optical communication system, cesium atomic time reference, pulse generator, quantum optics and other fields.

- Low insertion loss
- High damage power
- Low half-wave voltage
- High stability



Applications

- Fiber optic sensing system
- Pulsed light modulation system

Features

- Pulse light generator
- Analog transmission link

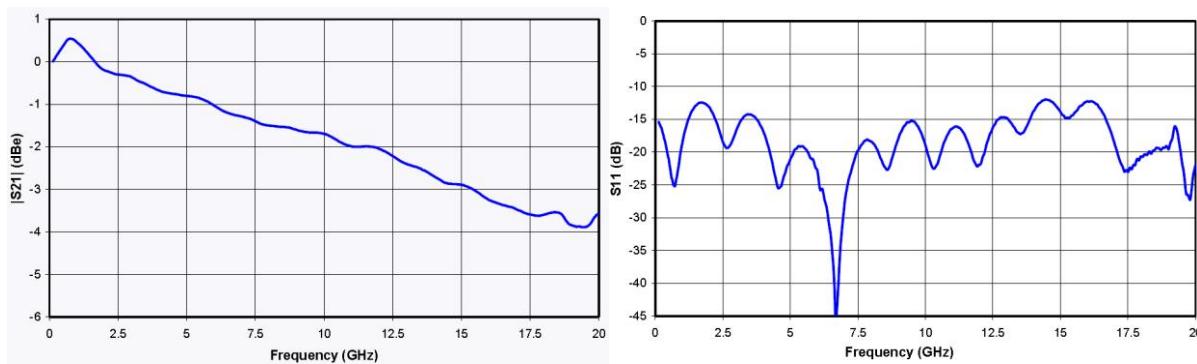
Performance parameter

Parameter	Symbol	Min	Typ	Max	Unit
Optical parameters					
Operating wavelength	λ	980	1060	1150	nm
Insertion loss	IL	-	4	5	dB
Optical return loss	ORL	-40	-45	-	dB
Switch extinction ratio@DC	ER@DC	20	23	-	dB
Dynamic extinction ratio	DER	12	13	-	dB
Optical fiber	Input port		PM fiber 980 nm		
	output port		PM fiber 980 nm		
Optical fiber interface			FC/PC、FC/APC Or user to specify		
Electrical parameters					
Operating bandwidth (-3dB)	S_{21}	300			MHz
Half-wave	RF	V π		3	3.5
Electrical return loss		S_{11}		-12	-10
Input impedance	RF	Z_{RF}	50		
	Bias	Z_{BIAS}	1M		
Electrical interface			SMA		
Bias pin definition			1,2-Bias 3,4- N/C		

Limit Conditions

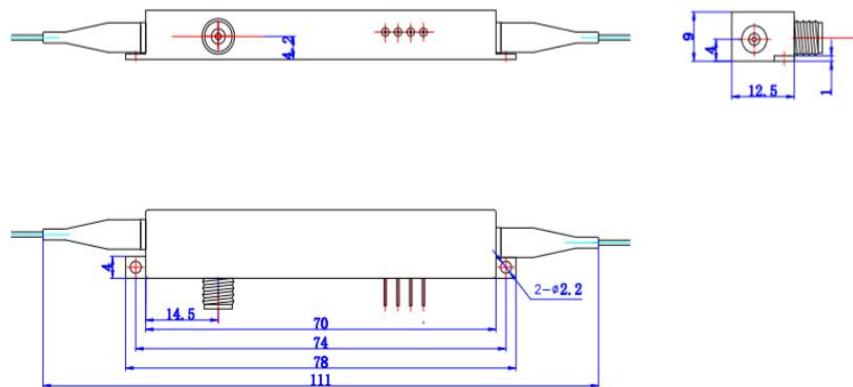
Parameter	Symbol	Unit	Min	Typ	Max
Input optical power	P _{in,Max}	dBm			20
Input RF power		dBm			28
Bias voltage	V _{bias}	V	-20		20
Operating temperature	Top	°C	0		70
Storage temperature	T _{st}	°C	-40		85
Humidity	RH	%	5		90

Characteristic curve



S₁₁&S₂₁Curve

Mechanical Diagram(mm)



Order information

Rof	AM	10	XX	XX	XX
	Modulator type: AM---Intensity modulator	Working wavelength: 10---1064nm	Operating bandwidth: 300M---DC- 300MHz 2.5G---2.5GHz 10G---10GHz	Optical fiber: PP---PM/PM	Facet: FA---FC/APC FP---FC/PC SP---User's customization

*please contact our sales if you have special requirements.

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ROF-AM-HER high extinction ratio of electro-optic modulator

ROF-AM-HER series high extinction ratio of electro-optic modulator based on M - Z push-pull structure intensity, has a lower half wave voltage and stable physical and chemical characteristics, using special technology to ensure the device with high extinction ratio of DC, and the device has high response speed, and therefore is widely used in light pulse generator, optical fiber sensing, laser radar, and other fields.

Features

- The extinction ratio is greater than 40dB
- Low insertion loss
- High modulation bandwidth
- Low half wave voltage

Applications

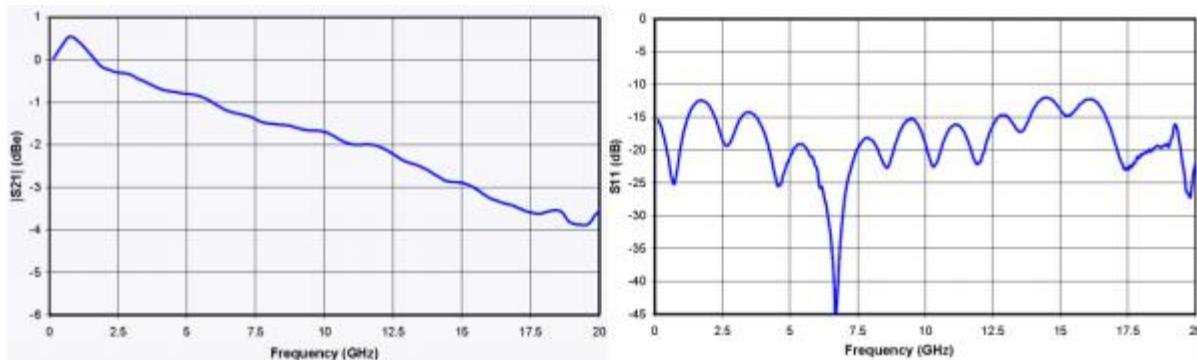
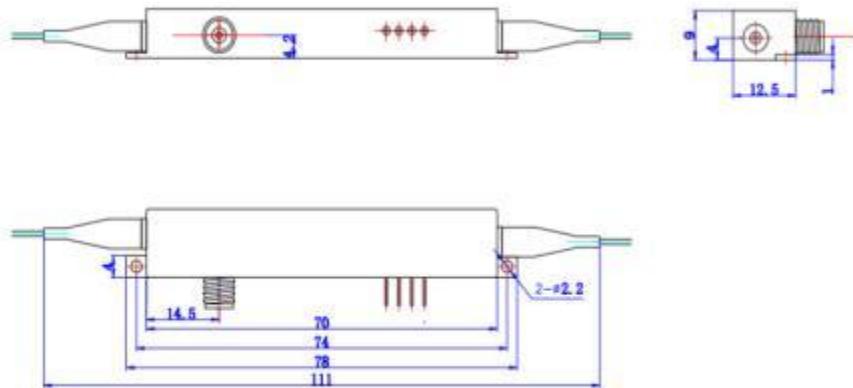
- Optical pulse generator
- Brillouin sensing system
- Laser radar

Performance

Parameter	Symbol	Min	Typ	Max	Unit
Optical parameters					
Operating wavelength	λ	1525		1565	nm
Insertion loss	IL		4	5	dB
Optical return loss	ORL			-45	dB
Switch extinction ratio@DC	ER@DC	35	40	50	dB
Dynamic extinction ratio		Panda PM			
Optical fiber	Input port	Panda PM or SMF-28			
Fiber interface		FC/PC、FC/APC Or user to specify			
Electrical parameters					
Operating bandwidth (-3dB)	S ₂₁	10	12		GHz
Half-wave	RF	Vπ@50KHz		5	V
	Bias	Vπ@Bias		7	V
Electrical return loss	S ₁₁		-12	-10	dB
Input impedance	RF	Z _{RF}	50		Ω
	Bias	Z _{BIA} S	10000		Ω
Operating bandwidth (-3dB)		SMA(f)			

**Limit Conditions**

Parameter	Symbol	Min	Typ	Max	Parameter
Input optical power	P _{in, Max}	dBm			20
Input RF power		dBm			28
Bias voltage	V _{bias}	V	-20		20
Operating temperature	T _{op}	°C	-10		60
Storage temperature	T _{st}	°C	-40		85
Humidity	RH	%	5		90

CharacteristicS₁₁&S₂₁Curve**Mechanical Diagram(mm)****Order information**

ROF	AM	HER	XX	XX	XX	XX
	Intensity modulator	High extinction ratio	Wavelength: 15--- 1550nm	Bandwidth: 2.5---2.5GHz 10G--- 10GHz 20G--- 18GHz	Optical fiber: PP---PMF-PMF PS---PMF-SMF	Facet: FA---FC/APC FP---FC/PC SP---User's customization

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Features

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Applications

- ROF systems
- Quantum key distribution
- Laser sensing systems
- Side-band modulation

Wavelength

- 850nm
- 1064nm
- 1310nm
- 1550nm

Bandwidth

- 300MHz
- 2.5GHz
- 10GHz
- 20GHz

Operating wavelength	850nm	1064nm	1310nm	1550nm	
3dB Bandwidth	~10GHz	~10GHz	~10GHz	~10GHz	~20GHz
Insertion Loss	<5dB	<5dB	<5dB	<5dB	
Extinction ratio @DC	> 23dB	> 23dB	> 23dB	> 23dB	
V _H @RF (1KHz)	< 3V	< 4V	< 4.5V	< 5.5V	< 6V
V _H @Bias	< 3.5V	< 5V	< 6V	< 7V	

Ordering Information

R	AM	15	10G	XX	XX
	Type: AM---Intensity Modulator	Wavelength: 08---850nm 10---1060nm 13---1310nm 15---1550nm	3dB bandwidth: 2.5G---10GHz 10G---10GHz 20G---20GHz 40G---28GHz	In-Out Fiber type: PP---PM/PM PS---PM/SMF	Optical connector: FA --- FC/APC FP --- FC/PC SP --- Customization

**R-AM-15-10G****Wavelength 1550nm 10GHz Intensity modulator**

Parameter	Symbol	Min	Typ	Max	Unit			
Optical parameters								
Operating wavelength	λ	1530	1550	1565	nm			
Insertion loss	IL		4	5	dB			
Optical return loss	ORL			-45	dB			
Switch extinction ratio @DC	ER@DC	20	25	45	dB			
Dynamic extinction ratio	DER		13		dB			
Optical fiber	Input port		Panda PM Fujikura SM					
	output port		Panda PM Fujikura SM					
Optical fiber interface		FC/PC、 FC/APC Or user to specify						
Electrical parameters								
Operating bandwidth (-3dB)	S_{21}	10	12		GHz			
Half-wave voltage V_{pi}	RF	@50KHz		4.5	5			
	Bias	@Bias		6	7			
Electrical return loss	S_{11}		-12	-10	dB			
Input impedance	RF	Z_{RF}	50		Ω			
	Bias	Z_{BIAS}	1M		Ω			
Electrical interface		SMA(f)						

Limit Conditions

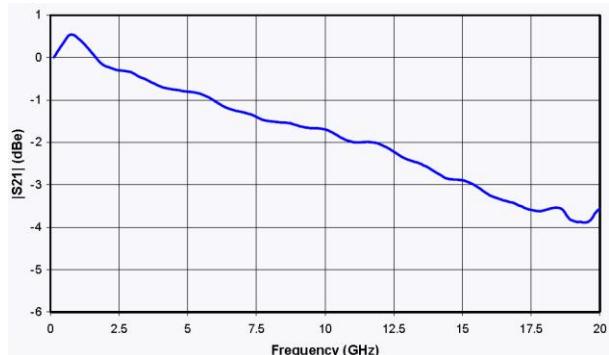
Parameter	Symbol	Unit	Min	Typ	Max
Input optical power	$P_{in,Max}$	dBm			20
Input RF power		dBm			28
bias voltage	V_{bias}	V	-20		20
Operating temperature	Top	°C	-10		60
Storage temperature	Tst	°C	-40		85
Humidity	RH	%	5		90



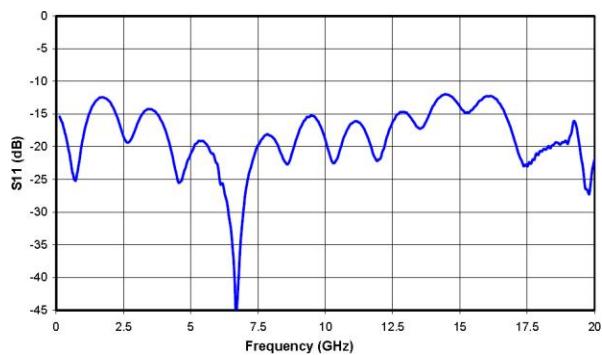
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S21 Curve

&S11 Curve

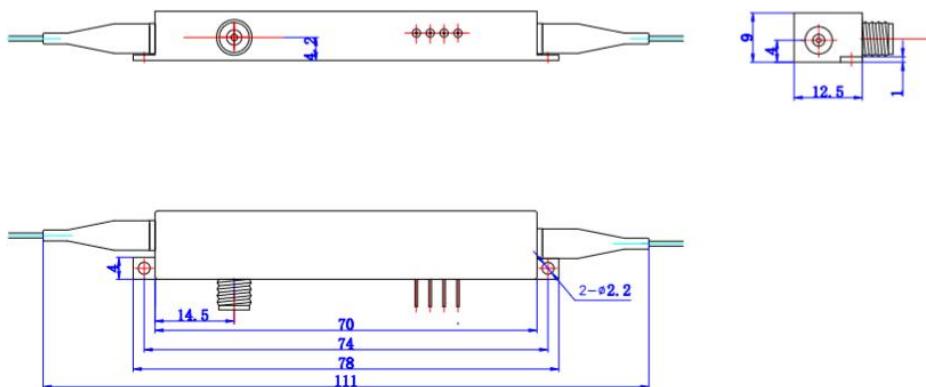


S21 Curve



S11 Curve

Mechanical Diagram



ordering information:

ROF	AM	10	XX	XX	XX
	Modulator type : AM---intensity modulator	Operating wavelength : 10---1064nm	Operating bandwidth : 2.5G---2.5GHz 10G---10GHz 20G---20GHz	Input output optical fiber: PS---PM/SMF PM--- PM/PMF	Connector: FA---FC/APC FP---FC/PC SP---user specified

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Operating wavelength	850nm	1064nm	1310nm	1550nm	
3dB Bandwidth	~10GHz	~10GHz	~10GHz	~10GHz	~20GHz
Insertion Loss	<5dB	<5dB	<5dB	<5dB	
Extinction ratio @DC	> 23dB	> 23dB	> 23dB	> 23dB	
V _H @RF (1KHz)	< 3V	< 4V	< 4.5V	< 5.5V	< 6V
V _H @Bias	< 3.5V	< 5V	< 6V	< 7V	

Ordering Information

R	AM	15	10G	XX	XX
	Type: AM---Intensity Modulator	Wavelength: 08---850nm 10---1060nm 13---1310nm 15---1550nm	3dB bandwidth: 2.5G---10GHz 10G---10GHz 20G---20GHz 40G---28GHz	In-Out Fiber type: PP---PM/PM PS---PM/SMF	Optical connector: FA --- FC/APC FP --- FC/PC SP --- Customization

**R-AM-15-20G****Wavelength 1550nm 20GHz Intensity modulator**

Parameter	Symbol	Min	Typ	Max	Unit			
Optical parameters								
Operating wavelength	λ	1530	1550	1565	nm			
Insertion loss	IL		4	5	dB			
Optical return loss	ORL			-45	dB			
Switch extinction ratio @DC	ER@DC	20	25	45	dB			
Dynamic extinction ratio	DER		13		dB			
Optical fiber	Input port		Panda PM Fujikura SM					
	output port		Panda PM Fujikura SM					
Optical fiber interface		FC/PC、 FC/APC Or user to specify						
Electrical parameters								
Operating bandwidth (-3dB)	S_{21}	18	20		GHz			
Half-wave voltage V_{pi}	RF	@50KHz		4.5	5			
	Bias	@Bias		6	7			
Electrical return loss	S_{11}		-12	-10	dB			
Input impedance	RF	Z_{RF}	50		Ω			
	Bias	Z_{BIAS}	1M		Ω			
Electrical interface		SMA(f)						

Limit Conditions

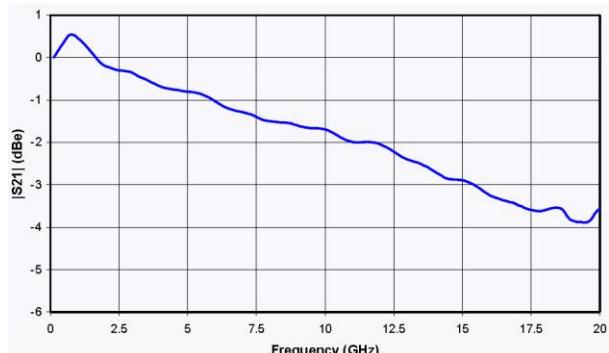
Parameter	Symbol	Unit	Min	Typ	Max
Input optical power	$P_{in,Max}$	dBm			20
Input RF power		dBm			28
bias voltage	V_{bias}	V	-20		20
Operating temperature	Top	°C	-10		60
Storage temperature	Tst	°C	-40		85
Humidity	RH	%	5		90



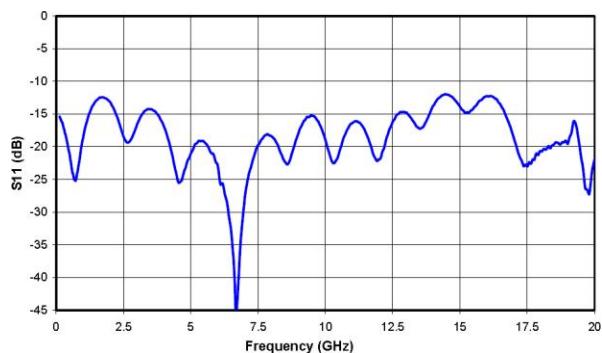
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S21 Curve

&S11 Curve

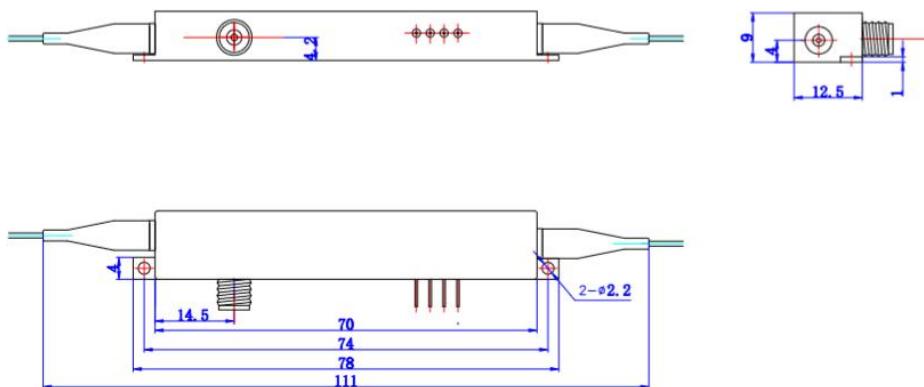


S21 Curve



S11 Curve

Mechanical Diagram



ordering information:

ROF	AM	10	XX	XX	XX
	Modulator type : AM---intensity modulator	Operating wavelength : 10---1064nm	Operating bandwidth : 2.5G---2.5GHz 10G---10GHz 20G---20GHz	Input output optical fiber: PS---PM/SMF PM--- PM/PMF	Connector: FA---FC/APC FP---FC/PC SP---user specified

please contact me if you have special requirement

RF Driver and Bias control circuit board information are provided on website (www.bjrofoc.com), you can also contact us for more information by email (bjrofoc@rof-oc.com) or WhatsApp (+86-18978968297)



AM Series Intensity Modulator



Description

The LiNbO₃ intensity modulator is widely used in high-speed optical communication system, laser sensing and ROF systems because of well electro-optic performance. The R-AM series based on MZ push-pull structure and X-cut design, has stable physical and chemical characteristics, which can be applied both in laboratory experiments and industrial systems.

Features

- Low insertion loss
- High Bandwidth
- Low half-wave voltage
- Customization option

Applications

- ROF systems
- Quantum key distribution
- Laser sensing systems
- Side-band modulation

Wavelength

- 850nm
- 1064nm
- 1310nm
- 1550nm

Bandwidth

- 300MHz
- 2.5GHz
- 10GHz
- 20GHz

Operating wavelength	850nm	1064nm	1310nm	1550nm	
3dB Bandwidth	~10GHz	~10GHz	~10GHz	~10GHz	~20GHz
Insertion Loss	<5dB	< 5dB	< 5dB	< 5dB	
Extinction ratio @DC	> 23dB	> 23dB	> 23dB	> 23dB	
V _H @RF (1KHz)	< 3V	< 4V	<4.5V	<5.5V	<6V
V _H @Bias	< 3.5V	<5V	<6V	<7V	

Ordering Information

R	AM	15	10G	XX	XX
	Type: AM---Intensity Modulator	Wavelength: 08---850nm 10---1060nm 13---1310nm 15---1550nm	3dB bandwidth: 2.5G---10GHz 10G---10GHz 20G---20GHz 40G---28GHz	In-Out Fiber type: PP---PM/PM PS---PM/SMF	Optical connector: FA --- FC/APC FP --- FC/PC SP --- Customization

**R-AM-15-40G****Wavelength 1550nm 40GHz Intensity modulator**

Parameter	Symbol	Min	Typ	Max	Unit			
Optical parameters								
Operating wavelength	λ	1525	1550	1565	nm			
Insertion loss	IL		4	5	dB			
Optical return loss	ORL			-45	dB			
Switch extinction ratio @DC	ER@DC	20	23	45	dB			
Dynamic extinction ratio	DER		13		dB			
Optical fiber	Input port		Panda PM					
	output port		Panda PM or SMF-28					
Optical fiber interface		FC/PC、 FC/APC Or user to specify						
Electrical parameters								
Operating bandwidth (-3dB)	S_{21}	26	28	30	GHz			
Half-wave voltage V _{pi}	RF	@1KHz		5	5.5			
	Bias	@1KHz		6	7			
Electrical return loss	S_{11}		-12	-10	dB			
Input impedance	RF	Z_{RF}	50					
	Bias	Z_{BIAS}	1M					
Electrical interface		SMA(f)						

Limit Conditions

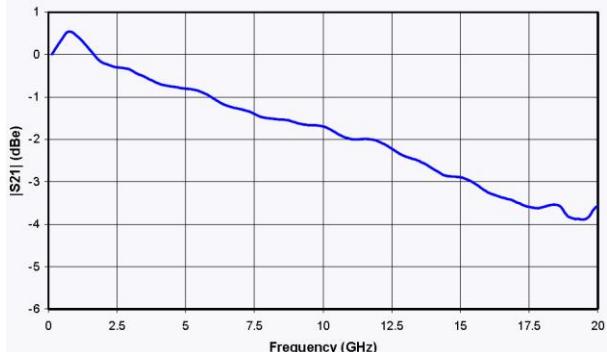
Parameter	Symbol	Unit	Min	Typ	Max
Input optical power@850nm	$P_{in,Max}$	dBm			20
Input RF power		dBm			28
bias voltage	V _{bias}	V	-20		20
Operating temperature	Top	°C	-10		60
Storage temperature	T _{st}	°C	-40		85
Humidity	RH	%	5		90



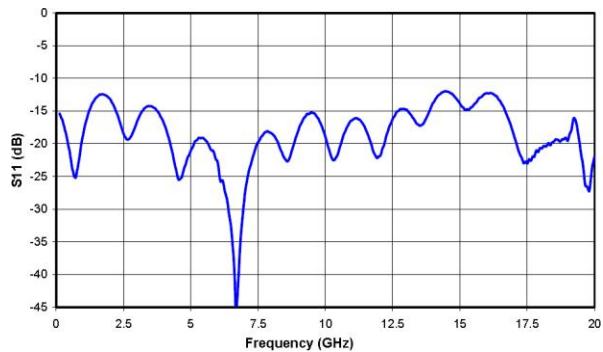
Beijing Rofea Optoelectronics Co., Ltd.

S21 Curve

&S11 Curve

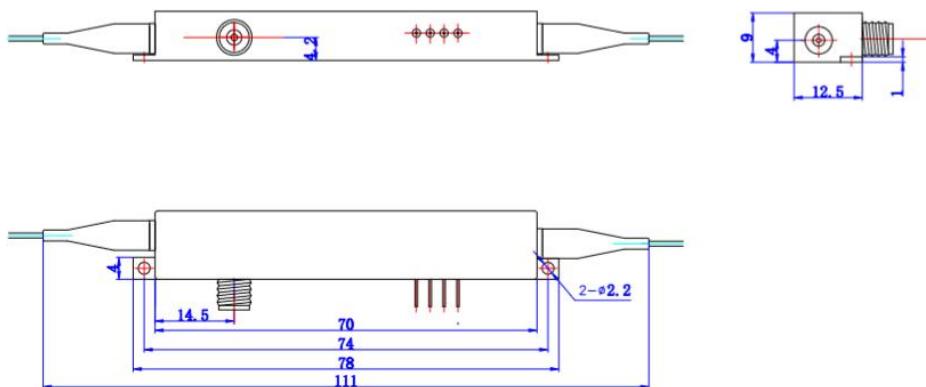


S21 Curve



S11 Curve

Mechanical Diagram



ordering information:

ROF	AM	10	XX	XX	XX
	Modulator type : AM---intensity modulator	Operating wavelength : 10---1064nm	Operating bandwidth : 2.5G---2.5GHz 10G---10GHz 20G---20GHz	Input output optical fiber: PS---PM/SMF PM--- PM/PMF	Connector: FA---FC/APC FP---FC/PC SP---user specified

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R-AM 1064nm Intensity Modulator

R-AM series 1064nm lithium niobate electro-optic intensity modulator adopts advanced proton exchange technology. It has the characteristics of low insertion loss, high modulation bandwidth, low half-wave voltage and so on , and mainly used in space optical communication system, cesium atomic time reference, pulse generator, quantum optics and other fields.

Features

- Low insertion loss
- High damage power
- Low half-wave voltage
- High stability



Applications

- Fiber optic sensing system
- Pulsed light modulation system
- Pulse light generator
- Analog transmission link

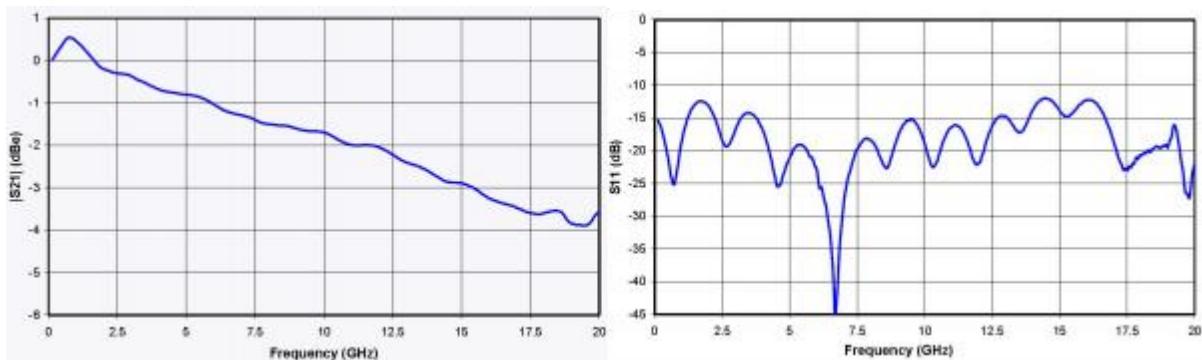
Performance parameter

Parameter	Symbol	Min	Typ	Max	Unit
Optical parameters					
Operating wavelength	λ	980	1060	1150	nm
Insertion loss	IL	-	4	5	dB
Optical return loss	ORL	-40	-45	-	dB
Switch extinction ratio@DC	ER@ DC	20	23	-	dB
Dynamic extinction ratio	DER	12	13	-	dB
Optical fiber	Input port		PM fiber 980 nm		
	output port		PM fiber 980 nm		
Optical fiber interface			FC/PC 、 FC/APC Or user to specify		
Electrical parameters					
Operating bandwidth (-3dB)	S_{21}	0.01~2.5 、 0.01~10			GHz
Bandwidth fluctuation	ΔS_{21}		0.5	1	dB
Half-wave	RF	$V\pi@50KHz$	3	3.5	V
	Bias	$V\pi@Bias$	3.5	4	V
Electrical return loss	S_{11}		-12	-10	dB
Input impedance	RF	Z_{RF}	50		Ω
	Bias	Z_{BIAS}	1M		Ω
Electrical interface			SMA		
Bias pin definition			1,2-Bias 3,4- N/C		

Limit Conditions

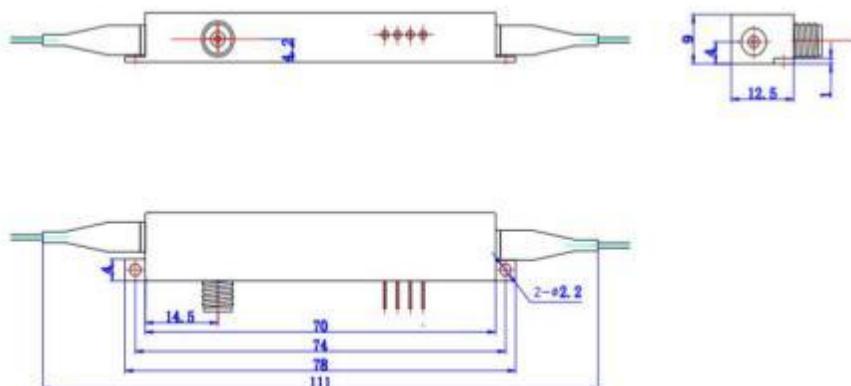
Parameter	Symbol	Unit	Min	Typ	Max
Input optical power	$P_{in, Max}$	dBm			20
Input RF power		dBm			28
Bias voltage	Vbias	V	-20		20
Operating temperature	Top	°C	0		70
Storage temperature	Tst	°C	-40		85
Humidity	RH	%	5		90

Characteristic curve



S₁₁&S₂₁Curve

Mechanical Diagram(mm)



Order information

R	AM	10	XX	XX	XX
	Modulator type: AM---Intensity modulator	Working wavelength: 10--- 1064nm	Operating bandwidth: 2.5G---2.5GHz 10G--- 10GHz	Optical fiber: PP---PM/PM	Facet: FA---FC/APC FP---FC/PC SP---User's customization

* please contact our sales if you have special requirements.

